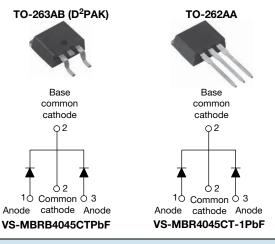
VS-MBRB4045CTPbF, VS-MBR4045CT-1PbF

Vishay Semiconductors

epoxy

High Performance Schottky Rectifier, 2 x 20 A



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PRODUCT SUMMARY						
Package	TO-263AB (D ² PAK), TO-262AA					
I _{F(AV)}	40 A					
V _R	45 V					
V _F at I _F	0.58 V					
I _{RM} max.	95 mA at 125 °C					
T _J max.	150 °C					
Diode variation	Common cathode					
E _{AS}	20 mJ					

FEATURES

High

- 150 °C T_J operation
- Low forward voltage drop
- High frequency operation

purity,

• Center tap TO-220, D²PAK and TO-262 packages



encapsulation for enhanced mechanical FREE strength and moisture resistance
Guard ring for enhanced ruggedness and long term

high temperature

- reliability • Meets MSL level 1, per J-STD-020, LF maximum peak
- of 260 °C
- AEC-Q101 qualified
 Material categorization: for definition
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

The center tap Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	VALUES	UNITS			
I _{F(AV)}	Rectangular waveform (per device)	40	٨			
I _{FRM}	T _C = 118 °C (per leg)	40	A			
V _{RRM}		45	V			
I _{FSM}	t _p = 5 μs sine	900	А			
V _F	20 A _{pk} , T _J = 125 °C	0.58	V			
TJ	Range	-65 to +150	°C			

VOLTAGE RATINGS						
PARAMETER	SYMBOL	VS-MBRB4045CTPbF VS-MBR4045CT-1PbF	UNITS			
Maximum DC reverse voltage	V _R	45	V			
Maximum working peak reverse voltage	V _{RWM}	45	v			

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDI	TEST CONDITIONS				
Maximum average per leg			T 110 °C reted V		20		
forward current per device	I _{F(AV)}	T _C = 118 °C, rated V _R	40				
Peak repetitive forward current per leg	I _{FRM}	Rated V _R , square wave, 20 kHz, T _C = 118 °C		40	А		
Maximum peak one cycle non-repetitive	1	5 µs sine or 3 µs rect. pulse	Following any rated load condition and with rated	900			
peak surge current per leg	IFSM	10 ms sine or 6 ms rect. pulse	V _{RRM} applied	210			
Non-repetitive avalanche energy per leg	E _{AS}	T _J = 25 °C, I _{AS} = 3 A, L = 4.4 mH		20	mJ		
Repetitive avalanche current per leg	I _{AR}	Current decaying linearly to zero Frequency limited by T _J maximu		3	А		

Revision: 15-Jul-14

Document Number: 94311

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ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS	
		20 A	T, = 25 °C	0.60	V	
Maximum forward voltage drep	V _{FM} ⁽¹⁾	40 A	1j=25 C	0.78		
Maximum forward voltage drop	VFM ("	20 A	T 105 %O	0.58		
		40 A	T _J = 125 °C	0.75		
	I _{RM} ⁽¹⁾	T _J = 25 °C		1	mA	
Maximum instantaneous reverse current		T _J = 100 °C	Rated DC voltage	50		
		T _J = 125 °C		95		
Maximum junction capacitance	C _T	$V_R = 5 V_{DC}$ (test signal ran	900	pF		
Typical series inductance	L _S	Measured from top of terr	8.0	nH		
Maximum voltage rate of change	dV/dt	Rated V _R	10 000	V/µs		

Note

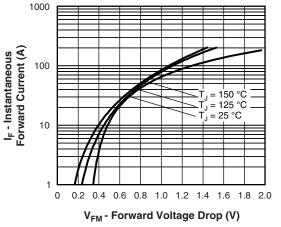
 $^{(1)}$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

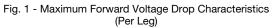
THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	TEST CONDITIONS	ITIONS VALUES				
Maximum junction temperature range	TJ		-65 to +150	°C		
Maximum storage temperature range	T _{Stg}		-65 to +175	-0		
Maximum thermal resistance, junction to case per leg	R _{thJC}	DC operation	1.5			
Typical thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth and greased (Only for TO-220)		°C/W		
Maximum thermal resistance, junction to ambient	R _{thJA}	DC operation (For D ² PAK and TO-262)	50			
Approving to weight			2	g		
Approximate weight			0.07	oz.		
Mounting torgue		Non-lubricated threads	6 (5)	kgf · cm		
Mounting torque maximum		Non-Iubricated trireads	12 (10)	(lbf · in)		
Marking davias		Case style D ² PAK	MBRB4	045CT		
Marking device		Case style TO-262	MBR40	45CT-1		

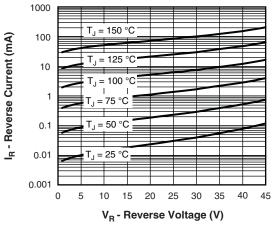


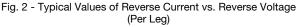
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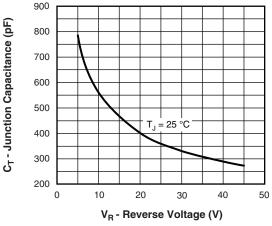


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

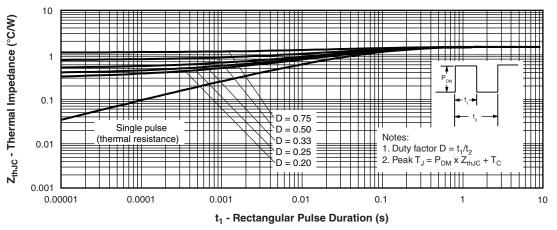
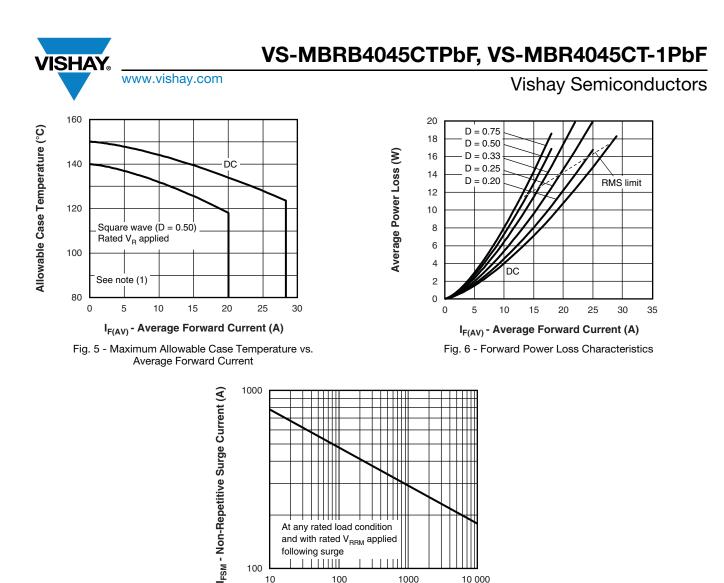
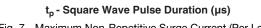


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Leg)

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1000

10 000

following surge 1 | | | | | |

100

100

10

Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$; $Pd = forward power loss = I_{F(AV)} \times V_{FM} at (I_{F(AV)}/D)$ (see fig. 6); $Pd_{REV} = inverse power loss = V_{R1} \times I_R (1 - D)$; $I_R at V_{R1} = rated V_R$



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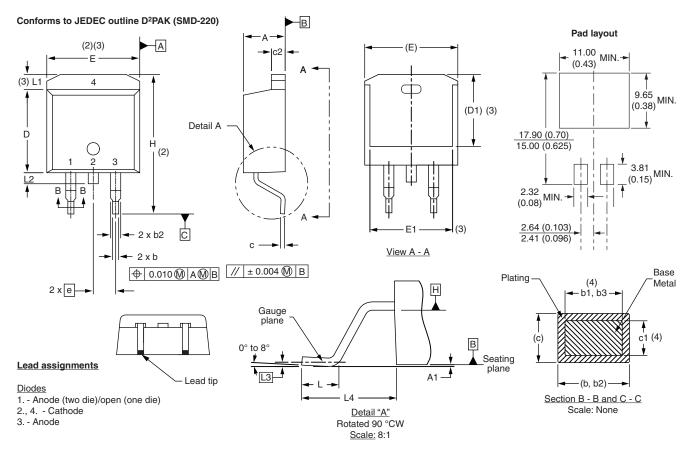
ORDERING INFORMATION TABLE

Device code	VS-	MBR	В	40	45	СТ	-1	TRL	PbF
	1	2	3	4	5	6	7	8	9
	1 2 3 4 5 6 7	- Ess - • B • N - Cur - Voli - CT - • N	ential pa = D ² PA one = T rent rati tage rati	O-262 [ng (40 = ng (45 = tial part ² PAK [7 Not 7 = - 40 A) 45 V)	ne 1 r			
	8			ibe (50 p	,				
	9	• TI - • Pi	RR = tap bF = lea	e and re be and r d (Pb)-f Pb)-free	eel (righ ree (for	nt orient TO-262	ed - for 2 and D ²	D ² PAK ² PAK tu	only)

LINKS TO RELATED DOCUMENTS							
Dimensions www.vishay.com/doc?95014							
Part marking information	www.vishay.com/doc?95008						
Packaging information	www.vishay.com/doc?95032						
SPICE model	www.vishay.com/doc?95296						

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D²PAK, TO-262



DIMENSIONS - D²PAK in millimeters and inches

SHA

SYMBOL	MILLIN				MILLIMETERS		INCHES			HES	NOTES
STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES						
А	4.06	4.83	0.160	0.190							
A1	0.00	0.254	0.000	0.010							
b	0.51	0.99	0.020	0.039							
b1	0.51	0.89	0.020	0.035	4						
b2	1.14	1.78	0.045	0.070							
b3	1.14	1.73	0.045	0.068	4						
с	0.38	0.74	0.015	0.029							
c1	0.38	0.58	0.015	0.023	4						
c2	1.14	1.65	0.045	0.065							
D	8.51	9.65	0.335	0.380	2						

Notes

- $^{(1)}\,$ Dimensioning and tolerancing per ASME Y14.5 M-1994 $\,$
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- $^{(3)}\,$ Thermal pad contour optional within dimension E, L1, D1 and E1
- ⁽⁴⁾ Dimension b1 and c1 apply to base metal only
- ⁽⁵⁾ Datum A and B to be determined at datum plane H
- ⁽⁶⁾ Controlling dimension: inch

SYMBOL	MILLIMETERS		INCHES		MILLIMETERS INCHES NOTES		NOTES
STIVIDUL	MIN.	MAX.	MIN.	MAX.	NULES		
D1	6.86	8.00	0.270	0.315	3		
E	9.65	10.67	0.380	0.420	2, 3		
E1	7.90	8.80	0.311	0.346	3		
е	2.54	BSC	0.100 BSC				
Н	14.61	15.88	0.575	0.625			
L	1.78	2.79	0.070	0.110			
L1	-	1.65	-	0.066	3		
L2	1.27	1.78	0.050	0.070			
L3	0.25	BSC	0.010	BSC			
L4	4.78	5.28	0.188	0.208			

(7) Outline conforms to JEDEC outline TO-263AB

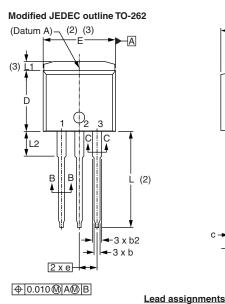
Outline Dimensions

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D²PAK, TO-262



DIMENSIONS - TO-262 in millimeters and inches

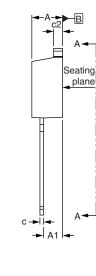


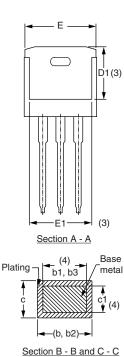
Lead tip

Diodes

3. - Anode

2., 4. - Cathode





Scale: None MILLIMETERS INCHES SYMBOL NOTES MIN. MAX. MIN. MAX. 4.06 4.83 0.160 0.190 А A1 2.03 3.02 0.080 0.119 b 0.51 0.99 0.020 0.039 0.51 0.89 0.020 0.035 4 b1 h2 1.14 1.78 0.045 0.070 b3 1.14 1.73 0.045 0.068 4 0.38 0.74 0.015 0.029 С 0.38 0.58 0.015 0.023 4 c1 1.14 0.045 0.065 c2 1.65 D 8.51 9.65 0.335 0.380 2 0.270 D1 6.86 8.00 0.315 3 Е 9.65 10.67 0.380 0.420 2, 3 E1 7.90 8.80 0.311 0.346 3 е 2.54 BSC 0.100 BSC L 13.46 14.10 0.530 0.555 L1 1.65 0.065 -3 L2 3.56 3.71 0.140 0.146 Notes

1. - Anode (two die)/open (one die)

⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994

⁽²⁾ Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

⁽³⁾ Thermal pad contour optional within dimension E, L1, D1 and E1

⁽⁴⁾ Dimension b1 and c1 apply to base metal only

⁽⁵⁾ Controlling dimension: inches

(6) Outline conform to JEDEC TO-262 except A1 (maximum), b (minimum) and D1 (minimum) where dimensions derived the actual package outline

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